

RD3H200SNFRA

Nch 45V 20A Power MOSFET

Datasheet

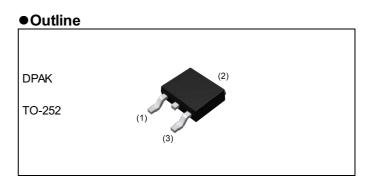
| V _{DSS} | 45V |
|----------------------------|------|
| R _{DS(on)} (Max.) | 28mΩ |
| Ι _D | ±20A |
| PD | 20W |

Features

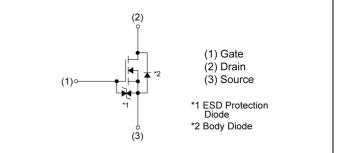
- 1) Low on resistance
- 2) Fast switching speed
- 3) Drive circuits can be simple
- 4) Parallel use is easy
- 5) Pb-free lead plating ; RoHS compliant
- 6) AEC-Q101 Qualified

Application

Switching



●Inner circuit



Packaging specifications

| | Packing | Embossed Tape |
|------|-----------------|------------------|
| | Reel size (mm) | 330 |
| Туре | Tape width (mm) | 16 |
| | Quantity (pcs) | 2500 |
| | Taping code | TL |
| | Marking | RD3H200SN |

• Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

| U V U | · / | | |
|--|--------------------|-------------|------|
| Parameter | Symbol | Value | Unit |
| Drain - Source voltage | V _{DSS} | 45 | V |
| Continuous drain current | I _D *1 | ±20 | А |
| Pulsed drain current | I _{DP} *2 | ±40 | А |
| Gate - Source voltage | V _{GSS} | ±20 | V |
| Power dissipation | P _D *3 | 20 | W |
| Junction temperature | Tj | 150 | °C |
| Operating junction and storage temperature range | T _{stg} | -55 to +150 | °C |

•Thermal resistance

| Parameter | Symbol | Values | | | Linit |
|-------------------------------------|-----------------|--------|------|------|-------|
| Farameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - case | R_{thJC}^{*3} | - | - | 6.25 | °C/W |

•Electrical characteristics (T_a = 25°C)

| Deremeter | Currente e l | Canditiana | Values | | | Linit | |
|--|---|--|--------|------|------|-------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = 1mA | 45 | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$ | I _D = 1mA referenced to 25°C | - | 46.8 | - | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 45V, V _{GS} = 0V | - | - | 1 | μA | |
| Gate - Source leakage current | I _{GSS} | V_{GS} = ±20V, V_{DS} = 0V | - | - | ±10 | μA | |
| Gate threshold voltage | $V_{GS(th)}$ | V _{DS} = 10V , I _D = 1mA | 1.0 | - | 2.5 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_j}$ | I _D = 1mA referenced to 25°C | - | -3.9 | - | mV/°C | |
| | | V _{GS} = 10V, I _D = 20A | - | 20 | 28 | | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | V _{GS} = 4.5V, I _D = 20A | - | 25 | 35 | mΩ | |
| | | V _{GS} = 4V, I _D = 20A | - | 28 | 40 | | |
| Gate resistance | R _G | f = 1MHz, open drain | - | 5.3 | - | Ω | |
| Forward Transfer Admittance | Y _{fs} ^{*4} | V _{DS} = 10V, I _D = 20A | 10 | - | - | S | |

*1 Limited only by maximum temperature allowed.

*2 Pw \leq 10µs , Duty cycle \leq 1%

*3 T_C=25°C

*4 Pulsed



• Electrical characteristics ($T_a = 25^{\circ}C$)

| Deremeter | Sumphal | Conditions | Values | | | Linit | |
|------------------------------|-------------------|-------------------------------------|--------|------|------|-------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 950 | - | | |
| Output capacitance | C _{oss} | V _{DS} = 10V | - | 250 | - | pF | |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 120 | - | | |
| Turn - on delay time | $t_{d(on)}^{*4}$ | $V_{DD} \simeq 25 V, V_{GS} = 10 V$ | - | 10 | - | | |
| Rise time | t _r *4 | I _D = 10A | - | 20 | - | 20 | |
| Turn - off delay time | $t_{d(off)}^{*4}$ | R _L ≃ 2.5Ω | - | 50 | - | ns | |
| Fall time | t_{f}^{*4} | R _G = 10Ω | - | 20 | - | | |

• Gate charge characteristics ($T_a = 25^{\circ}C$)

| Deremeter | Symbol | Conditions | | Values | | |
|----------------------|--------------------|------------------------|------|--------|------|------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Total gate charge | Q _g *4 | V _{DD} ≃ 25V, | - | 12 | - | |
| Gate - Source charge | Q _{gs} *4 | I _D = 20A, | - | 3.5 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | V _{GS} = 5V | - | 4.0 | - | |

•Body diode electrical characteristics (Source-Drain) ($T_a = 25^{\circ}C$)

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------------|--------------------|--|--------|------|------|------|
| Farameter | Symbol Condition | | Min. | Тур. | Max. | Unit |
| Continuous forward current | ۱ _s *1 | $T = 25^{\circ}$ | - | - | 16 | А |
| Pulse forward current | I _{SP} *2 | T _a = 25°C | - | - | 40 | А |
| Forward voltage | V_{SD}^{*4} | V _{GS} = 0V, I _S = 20A | - | - | 1.2 | V |



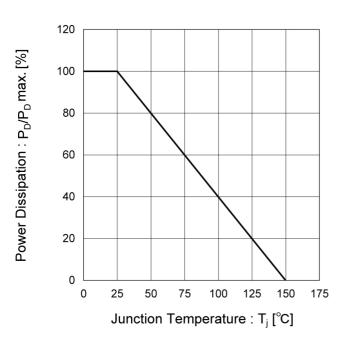


Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

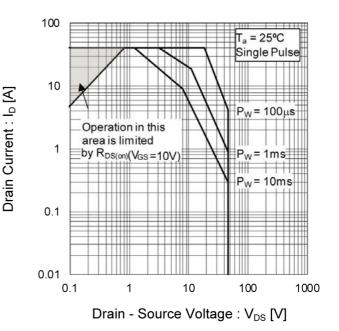
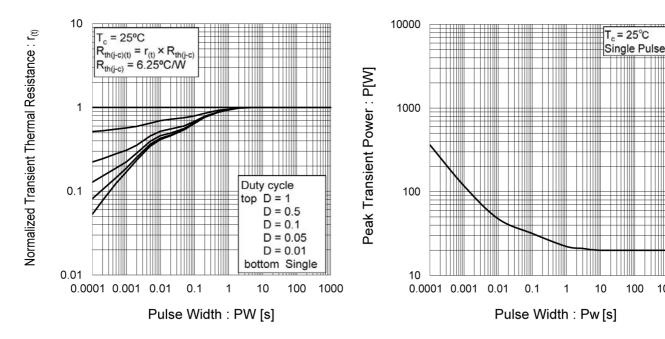


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

Fig.4 Single Pulse Maximum Power dissipation





1000

10

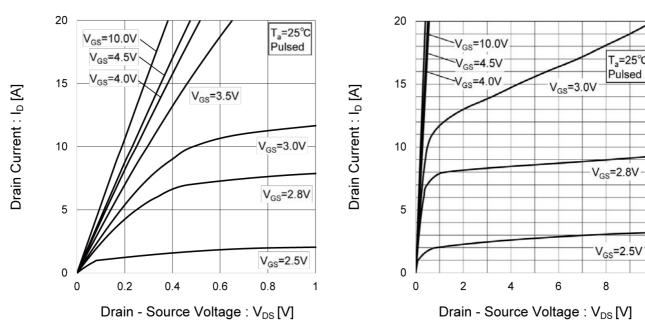
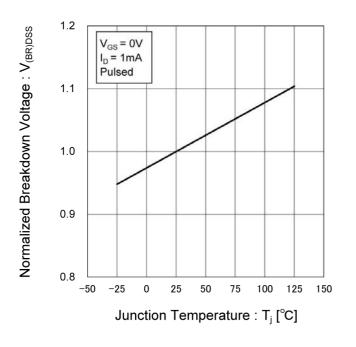


Fig.5 Typical Output Characteristics(I)

Fig.6 Typical Output Characteristics(II)

Fig.7 Breakdown Voltage vs. Junction Temperature





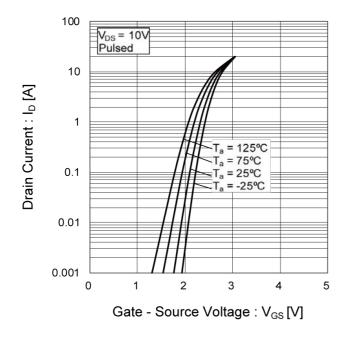


Fig.8 Typical Transfer Characteristics

Fig.9 Gate Threshold Voltage vs. Junction Temperature

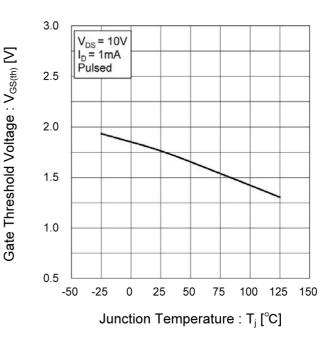
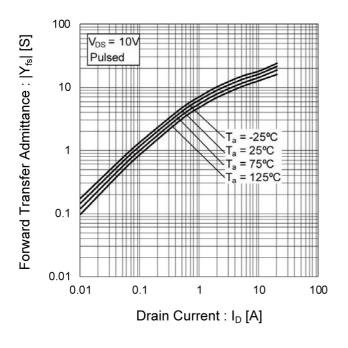


Fig.10 Forward Transfer Admittance vs. Drain Current





• Electrical characteristic curves

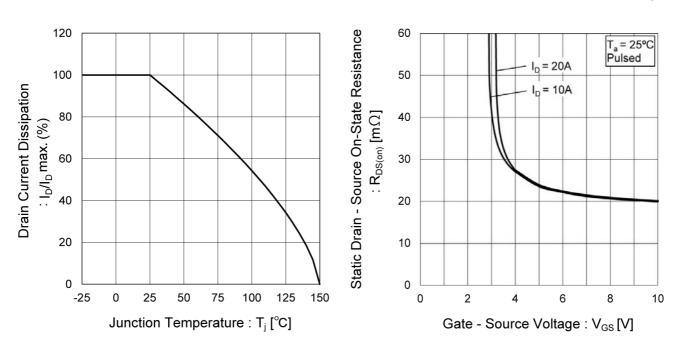
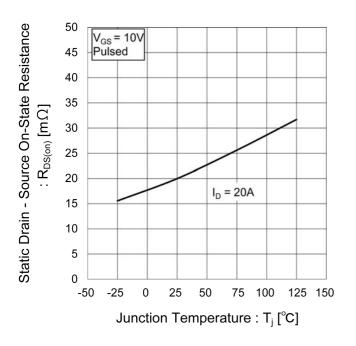


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature







• Electrical characteristic curves

Fig.14 Static Drain - Source On - State

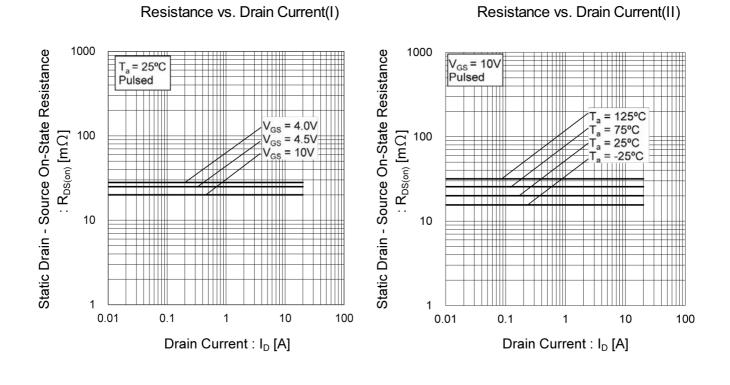
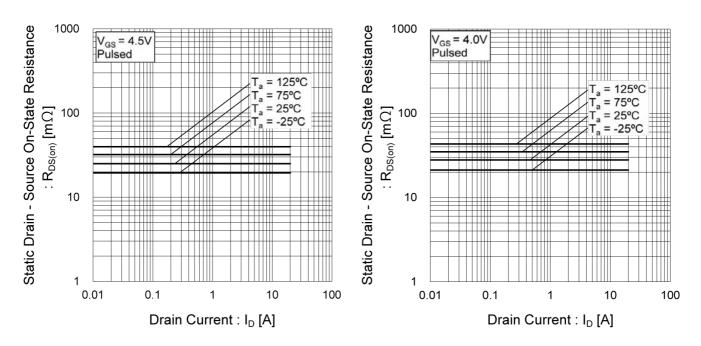


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III) Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

Fig.15 Static Drain - Source On - State





• Electrical characteristic curves

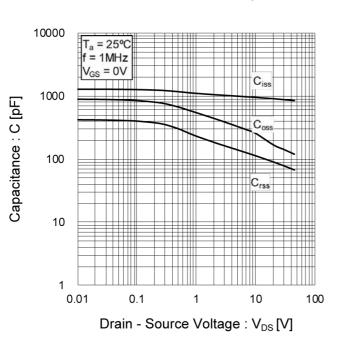


Fig.18 Typical Capacitance vs. Drain - Source Voltage

Fig.19 Switching Characteristics

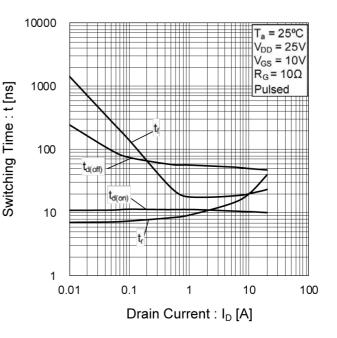


Fig.20 Dynamic Input Characteristics

Gate - Source Voltage : V_{GS} [V]

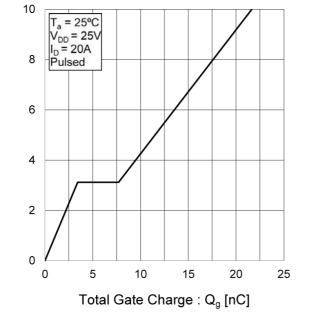
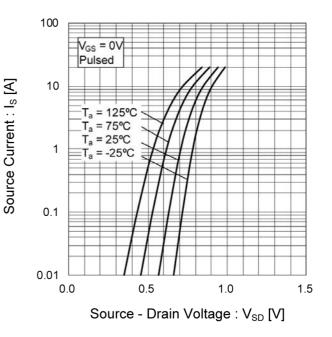


Fig.21 Source Current vs. Source Drain Voltage





• Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

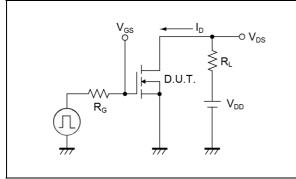


Fig.2-1 Gate Charge Measurement Circuit

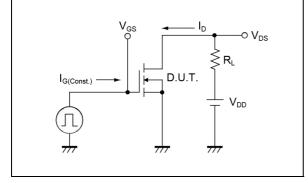
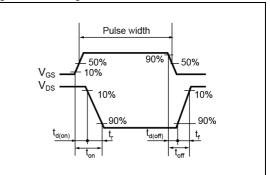
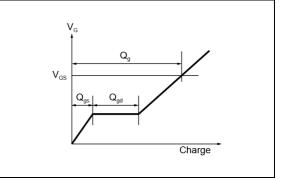


Fig.1-2 Switching Waveforms

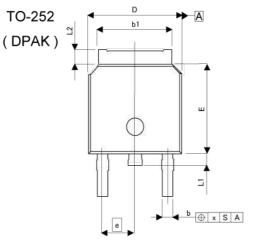


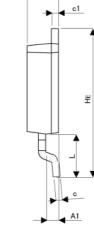


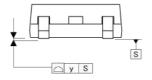


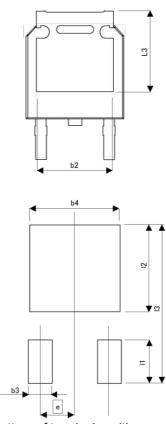


Dimensions









Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| | MILIME | ETERS | INC | HES |
|-------|--------|-------|-------|-------|
| DIM - | MIN | MAX | MIN | MAX |
| A | 2.10 | 2.30 | 0.083 | 0.091 |
| A1 | 0.70 | 1.10 | 0.028 | 0.043 |
| b | 0.65 | 0.85 | 0.026 | 0.033 |
| b1 | 5.10 | 5.40 | 0.201 | 0.213 |
| b2 | 5. | 10 | 0.2 | 201 |
| с | 0.40 | 0.60 | 0.016 | 0.024 |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 6.40 | 6.80 | 0.252 | 0.268 |
| е | 2. | 30 | 0.091 | |
| E | 6.00 | 6.40 | 0.236 | 0.252 |
| HE | 9.50 | 10.50 | 0.374 | 0.413 |
| L | 2. | 2.90 | | 14 |
| L1 | 0.70 | 0.90 | 0.028 | 0.035 |
| L2 | 0.70 | 1.30 | 0.028 | 0.051 |
| L3 | 5. | 30 | 0.2 | 209 |
| х | - | 0.10 | 141 | 0.004 |
| y | - | 0.10 | - | 0.004 |

| DIM - | MILIMETERS | | INC | HES |
|-------|------------|-------|-------------------|-------|
| | MIN | MAX | MIN | MAX |
| b3 | <i>2</i> | 1.10 | 64 <u>2</u> 8 | 0.043 |
| b4 | × | 5.40 | 3) | 0.213 |
| 11 | <u>12</u> | 2.90 | 7 <u>6</u> | 0.114 |
| 12 | | 5.50 | 5. 0) | 0.217 |
| 13 | 12 C | 10.50 | 023 | 0.413 |

Dimension in mm/inches



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| (Note1) Medical Equipment Classification of the Specific App | plications |
|--|------------|
|--|------------|

| JAPAN | USA | EU | CHINA |
|---------|-----------|------------|---------|
| CLASSII | CLASSⅢ | CLASS II b | CLASSII |
| CLASSIV | CLASS III | CLASSⅢ | CLASSII |

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
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 - [c] the Products are exposed to direct sunshine or condensation
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- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
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